DATA SHEET



MOS FIELD EFFECT TRANSISTOR Phase-out/Discontinued μ **ΡΑ1704**

SWITCHING N-CHANNEL POWER MOS FET **INDUSTRIAL USE**

DESCRIPTION

This µPA1704 is N-Channel MOS Field Effect Transistor designed for power management applications and Li-ion battery application.

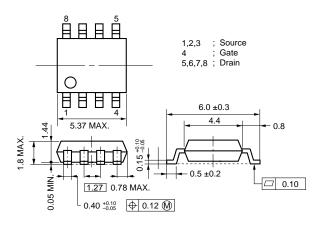
FEATURES

- · 2.5-V gate drive and low on-resistance $R_{DS(on)1} = 13 \text{ m}\Omega \text{ MAX.}$ (Vgs = 4.0 V, ID = 5.0 A) $R_{DS(on)2} = 16 \text{ m}\Omega \text{ MAX.} (V_{GS} = 2.5 \text{ V}, \text{ ID} = 5.0 \text{ A})$
- Low Ciss : Ciss = 2700 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μΡΑ1704G	Power SOP8

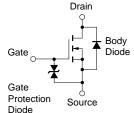
PACKAGE DRAWING (Unit : mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.)

Drain to Source Voltage (VGs = 0 V)	VDSS	30	V	
Gate to Source Voltage (VDS = 0 V)	Vgss	±12	V	EQUIVALENT
Drain Current (DC)	D(DC)	±10	А	Dra
Drain Current (pulse) ^{Note1}	D(pulse)	±40	А	c •
Total Power Dissipation $(T_A = 25^{\circ}C)^{Note2}$	Рт	2.0	W	Gate
Channel Temperature	Tch	150	°C	
Storage Temperature	Tstg	–55 to + 150	°C	Gate
Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %				Protection Sou





2. Mounted on ceramic substrate of 1200 mm² x 0.7 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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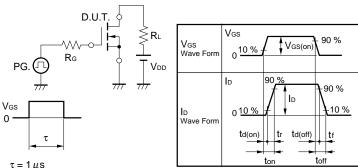
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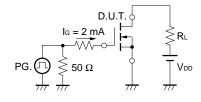
ELECTRICAL CHARACTERISTICS (TA = 25°C,	, All terminals are connected.)
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 4.0 V, Id = 5.0 A		9.8	13	mΩ
	RDS(on)2	Vgs = 2.5 V, Id = 5.0 A		12	16	mΩ
Gate to Source Cut-off Voltage	VGS(off)	Vds = 10 V, Id = 1 mA	0.5	0.8	1.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 5.0 A	10	25		S
Drain Leakage Current	IDSS	$V_{DS} = 30 V, V_{GS} = 0 V$			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 12 V$, $V_{DS} = 0 V$			±10	μA
Input Capacitance	Ciss	Vds = 10 V		2700		pF
Output Capacitance	Coss	Vgs = 0 V		880		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		400		pF
Turn-on Delay Time	td(on)	ID = 5.0 A		25		ns
Rise Time	tr	$V_{GS(on)} = 4.0 V$		95		ns
Turn-off Delay Time	td(off)	Vdd = 15 V		235		ns
Fall Time	tr	$R_G = 10 \Omega$		200		ns
Total Gate Charge	QG	ID = 10 A		38		nC
Gate to Source Charge	Q _{GS}	V _{DD} = 24 V		3.3		nC
Gate to Drain Charge	Qgd	Vgs = 4.0 V		15		nC
Body Diode Forward Voltage	VF(S-D)	IF = 10 A, VGS = 0 V		0.8		V
Reverse Recovery Time	trr	IF = 10 A, VGs = 0 V		48		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μs		53		nC

TEST CIRCUIT 1 SWITCHING TIME



TEST CIRCUIT 2 GATE CHARGE

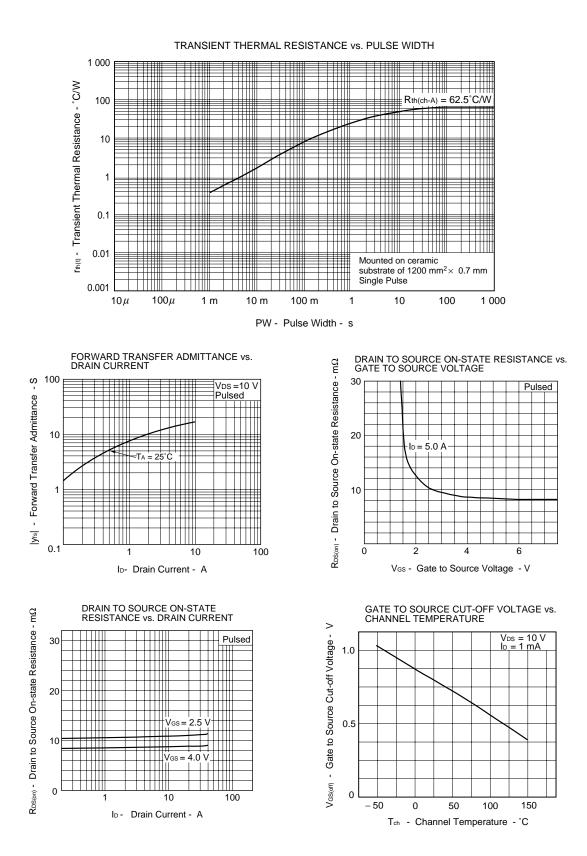


 $\tau = 1 \,\mu s$ Duty Cycle $\leq 1 \%$ NEC



μ PA1704

TYPICAL CHARACTERISTICS (TA = 25°C)



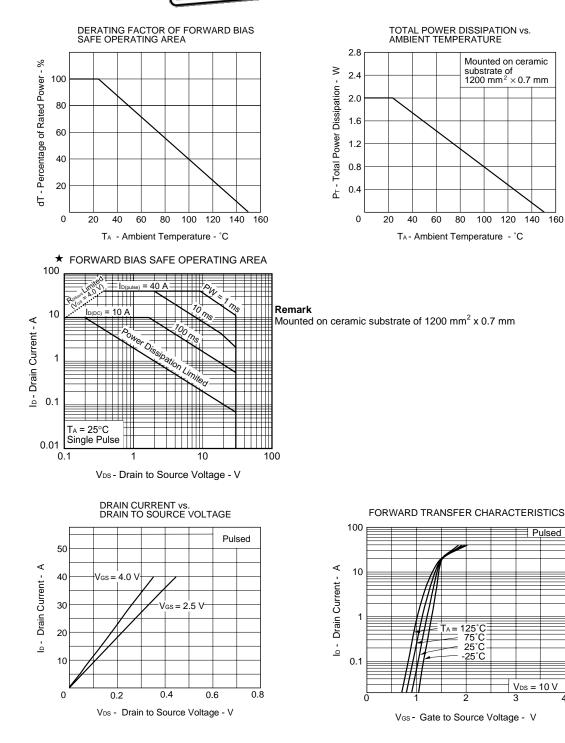
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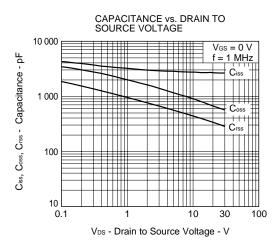


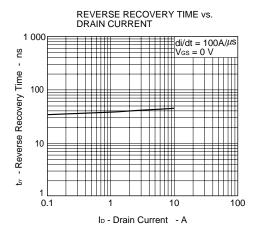
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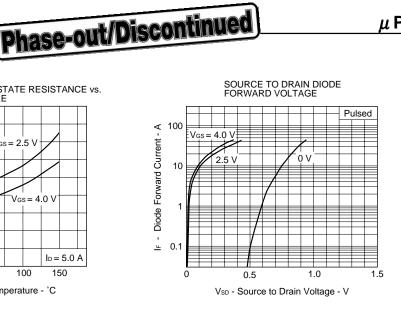
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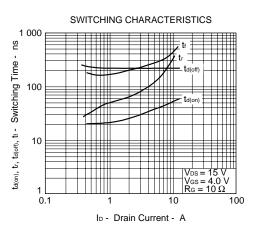
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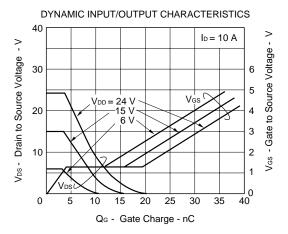
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE 20 $V_{GS} = 2.5 V$ $V_{GS} = 4.0 V$ $V_{GS} = 4.0 V$ $V_{GS} = 4.0 V$ $V_{GS} = 5.0 A$ T_{ch} - Channel Temperature - 'C











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